

Program: BC (CS) Subject: Basic Electronics Assignment Number: 02 Course Code: CSS-102 EDP Code: 101902011 Spring Semester 2019

## Q.1 Give answers to each of the following:

- 1. What is a crystal? Explain silicon crystal.
- 2. Discuss the recombination and life time.
- 3. Discuss the flow of free electron and hole in intrinsic semiconductor.
- 4. Discuss doping of a semiconductor using examples.
- 5. What is depletion layer and barrier potential?
- 6. Why there is a continuous flow of current in a forward biased diode?
- 7. Why ordinary diode shouldn't be operated in breakdown region?
- 8. Discuss different currents in the reverse biased diode.
- 9. What is the effect of temperature on barrier potential?
- 10. Why the reverse current in germanium diode is greater than silicon diode?

## Q.2 Differentiate between each of the following:

- 1. Conductors and Semiconductors
- 2. Silicon and Germanium
- 3. Extrinsic and Intrinsic semiconductors
- 4. Minority and Majority carriers in a semiconductor
- 5. n-type and p-type semiconductors
- 6. Forward biased and Reverse biased diode
- 7. p-type energy bands and n-type energy bands

## Q.3 Draw and explain each of the following diagrams/circuits:

- 1. Silicon crystal
- 2. pn-junction
- 3. Energy bands diagrams for intrinsic semiconductor
- 4. Energy bands diagrams for p-type and n-type semiconductors

## Q.4 Solve each of the following:

- 1. Suppose an outside force removes the valence electron from a copper atom. What is the net charge of the copper atom? What is the net charge if an outside electron moves into the valence orbit?
- 2. Assuming a barrier potential of 0.7 V at an ambient temperature of 25°C, what is the barrier potential of a silicon diode when the junction temperature is -40°C?
- 3. A silicon diode has a saturation current of 10nA at 25°C. Find saturation current at 93°C.
- 4. A diode has a surface-leakage current of 02nA at reverse voltage is 20V. What is the surface-leakage current if the reverse voltage is increased to 50V?